

NGTD13T65F2WP

NGTD13T65F2WP Information

Heisener.com	 NGTD13T65F2WP ON Semiconductor Discrete Semiconductor Products Transistors - IGBTs - Single IGBT TRENCH FIELD STOP 650V DIE Die For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote



Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



NGTD13T65F2WP Specifications

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Manufacturer Part Number	NGTD13T65F2WP
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	Die
Series	-
IGBT Type	Trench Field Stop
Voltage - Collector Emitter Breakdown (Max)	650V
Current - Collector (Ic) (Max)	-
Current - Collector Pulsed (Icm)	120A
Vce(on) (Max) @ Vge, Ic	2.2V @ 15V, 30A
Power - Max	-
Switching Energy	-
Input Type	Standard
Gate Charge	-
Td (on/off) @ 25°C	-
Test Condition	-
Reverse Recovery Time (trr)	-
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Surface Mount
Package / Case	Die
Supplier Device Package	Die
	Report errors?

NGTD13T65F2WP Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

NGTD13T65F2WP Payment Methods





If you have any question about NGTD13T65F2WP, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com